NSN 5961-01-169-2159

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-169-2159 **Inclosure Material:** Metal **Overall Length:** 4.702 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-93 **Mounting Method:** Threaded stud Thready Qty Per Inch (tpi): **Thread Size:** 0.750 inches **Criticality Code Justification:** Zzzy **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 off-state voltage, dc **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 3 insulated wire lead w/terminal lug **Reference Number Differentiating Characteristics:** Material will be in accordance with ships parts control center activity hx quality control, manufacturing and testing specifications Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: